

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

Choong Paul Kim, et al.

Application No.

10/735,148

Filed

: December 12, 2003

Title

IN-SITU DUCTILE METAL/BULK GLASS MATRIX COMPOSITES

FORMED BY CHEMICAL PARTITIONING

Grp./Div.

1742

Examiner

George P. Wyszomierski

Docket No. :

51667/RDS/C543

DECLARATION UNDER 37 C.F.R. 1.32

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 Post Office Box 7068 Pasadena, CA 91109-7068 August 21, 2006

Commissioner:

- I, William L. Johnson, declare and state as follows:
- 1. I am the same William L. Johnson who signed a Declaration filed in this application on November 11, 2005. I remain a qualified expert as described in that Declaration.
- 2. The technique described in the above-identified patent application produces a composite material having a ductile crystalline metal phase distributed in an amorphous metal matrix. This is obtained by cooling an alloy from the melt until a second phase forms in situ by homogeneous nucleation throughout the melt and followed by crystal growth. A composite having ductile metal particles precipitated in situ in an amorphous metal matrix exhibits ductility that is not present in a bulk metallic glass. Patterns of shear bands propagate through the amorphous metal matrix and through the ductile particles to produce overall ductility in the composite.

I hereby certify that this correspondence is being deposited with the U.S. Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.G. Box 1450, Alexandria, VA 22313-1450 on:

(Date of Deposit)

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Hall-Petch critical size limit for a brittle intermetallic compound would be substantially more than 20 nanometers, and that is not the only reason that the material is non-ductile. No appreciable dislocation slip occurs in such non-ductile materials.

I declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under 18 U.S.C. 1001 and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

William L. Johnson

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